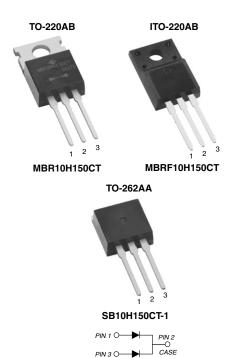


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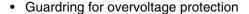
Dual Common-Cathode High-Voltage Schottky Rectifier

Low Leakage Current 5.0 μA



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 5 A			
V _{RRM}	150 V			
I _{FSM}	160 A			
V _F	0.72 V			
T _J	175 °C			

FEATURES





· Low power loss, high efficiency

(e3)

Low forward voltage drop

RoHS

· High frequency operation

• Solder dip 260 °C, 40 s

 Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency inverters, freewheeling and polarity protection applications.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-262AA Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class

1A whisker test

Mounting Torque: 10 in-lbs maximum

Polarity: As marked

PARAMETER	SYMBOL	MBR10H150CT	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	150	V
Working peak reverse voltage	V _{RWM}	150	V
Maximum DC blocking voltage	V_{DC}	150	V
Maximum average forward rectified current (Fig. 1) total device per diode	I _{F(AV)}	10 5	А
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	160	А
Peak repetitive reverse current per diode at $t_p = 2 \mu s$, 1 kHz	I _{RRM}	1.0	А
Peak non-repetitive reverse surge energy per diode (8/20 µs waveform)	E _{RSM}	10	mJ
Non-repetitive avalanche energy per diode at 25 °C, I_{AS} = 1.5 A, L = 10 mH	E _{AS}	11.25	mJ
Voltage rate of change (rated V _R)	dV/dt	10 000	V/µs
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to + 175	°C
Isolation voltage (ITO-220AB only) from terminals to heatsink t = 1 min	V _{AC}	1500	٧

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MBR10H150CT, MBRF10H150CT & SB10H150CT-1

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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
	I _F = 5.0 A	T _J = 25 °C		0.88	
Maximum instantaneous forward voltage per diode ⁽¹⁾	$I_F = 5.0 A$	T _J = 125 °C	V _F	0.72	V
	I _F = 10 A	$T_J = 25 ^{\circ}C$		0.96	
	I _F = 10 A	T _J = 125 °C		0.80	
Maximum reverse current per diode at working peak reverse voltage (1)		T _J = 25 °C T _J = 125 °C	I _R	5.0 1.0	μA mA

Note:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance per diode	$R_{ hetaJC}$	2.4	4.5	2.4	°C/W

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR10H150CT-E3/45	2.06	45	50/tube	Tube		
ITO-220AB	MBRF10H150CT-E3/45	2.20	45	50/tube	Tube		
TO-262AA	SB10H150CT-1E3/45	1.58	45	50/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

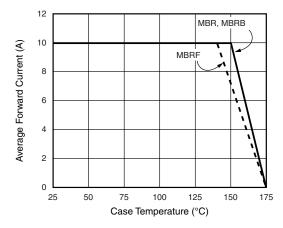


Figure 1. Forward Derating Curve (Total)

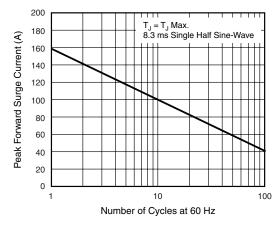


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode





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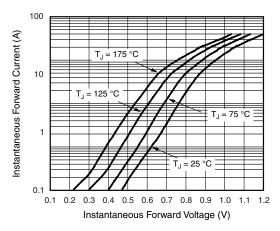


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

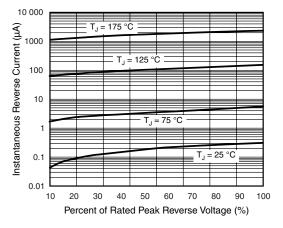


Figure 4. Typical Reverse Characteristics Per Diode

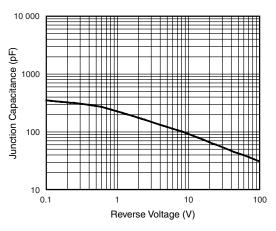


Figure 5. Typical Junction Capacitance Per Diode

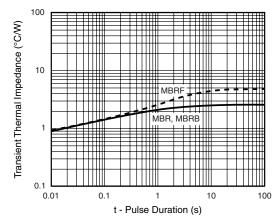


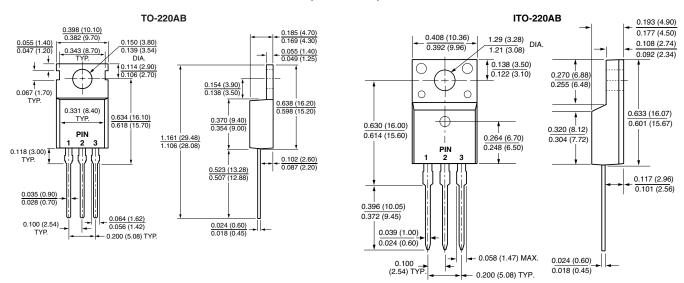
Figure 6. Typical Transient Thermal Impedance Per Diode

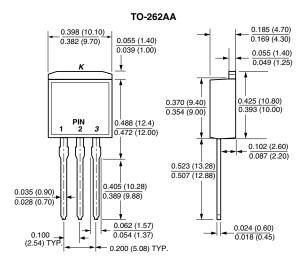
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)









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